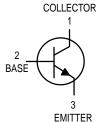
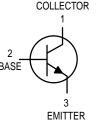
# **Amplifier Transistors** NPN Silicon

BC337,-16,-25,-40 BC338,-16,-25,-40

TO-92 (TO-226AA)





# CASE 29-04, STYLE 17

### **MAXIMUM RATINGS**

Rating	Symbol	BC337	BC338	Unit
Collector-Emitter Voltage	VCEO	45 25		Vdc
Collector-Base Voltage	Vсво	50	30	Vdc
Emitter-Base Voltage	VEBO	5.0		Vdc
Collector Current — Continuous	IC	800		mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.5 12		Watt mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150		°C

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ heta}$ JC	83.3	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0)	BC337 BC338	V <sub>(BR)</sub> CEO	45 25	_ _	_ _	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 100 \mu A, I_E = 0$ )	BC337 BC338	V(BR)CES	50 30	_ _	_ _	Vdc
Emitter-Base Breakdown Voltage (IE = 10 $\mu$ A, IC = 0)		V(BR)EBO	5.0	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 30 V, I <sub>E</sub> = 0) (V <sub>CB</sub> = 20 V, I <sub>E</sub> = 0)	BC337 BC338	ICBO	_ _	_ _	100 100	nAdc
Collector Cutoff Current (VCE = 45 V, VBE = 0) (VCE = 25 V, VBE = 0)	BC337 BC338	ICES	_ _	_ _	100 100	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 V, I <sub>C</sub> = 0)		I <sub>EBO</sub>	_	_	100	nAdc

**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS		•		-		
DC Current Gain (I <sub>C</sub> = 100 mA, $V_{CE}$ = 1.0 V) (I <sub>C</sub> = 300 mA, $V_{CE}$ = 1.0 V)	BC337/BC338 BC337–16/BC338–16 BC337–25/BC338–25 BC337–40/BC338–40	hFE	100 100 160 250 60	_ _ _ _	630 250 400 630	_
Base–Emitter On Voltage (IC = 300 mA, V <sub>CE</sub> = 1.0 V)		VBE(on)	_	_	1.2	Vdc
Collector-Emitter Saturation Voltage (IC = 500 mA, I <sub>B</sub> = 50 mA)		VCE(sat)	_	_	0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS		•	•	•	•	
Output Capacitance (V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1.0 MHz)		C <sub>ob</sub>	_	15	_	pF
Current-Gain — Bandwidth Product (IC = 10 mA, V <sub>CE</sub> = 5.0 V, f = 100 MHz)		fT	_	210	_	MHz

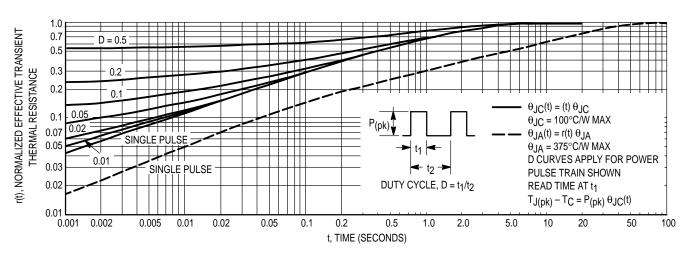


Figure 1. Thermal Response

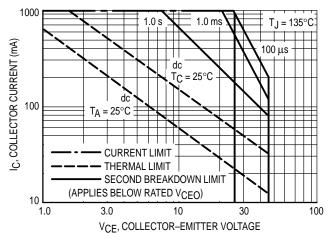


Figure 2. Active Region — Safe Operating Area

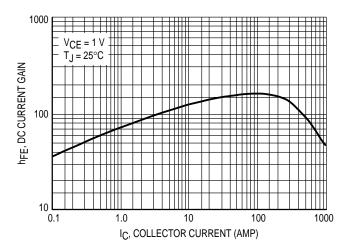


Figure 3. DC Current Gain

### BC337,-16,-25,-40 BC338,-16,-25,-40

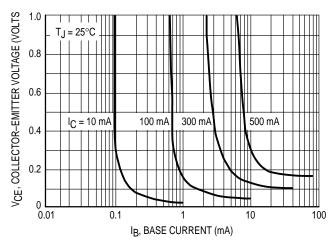


Figure 4. Saturation Region

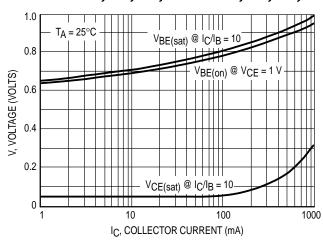
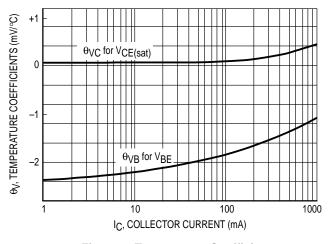


Figure 5. "On" Voltages



**Figure 6. Temperature Coefficients** 

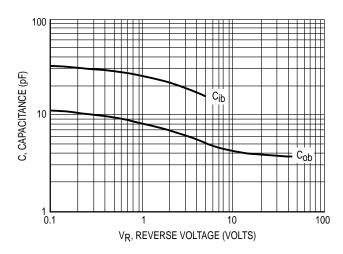
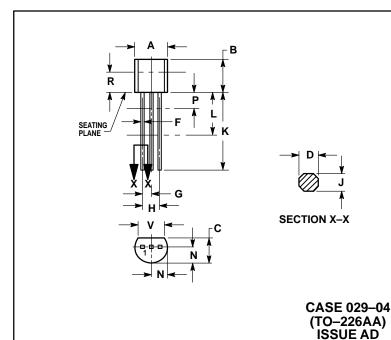


Figure 7. Capacitances

### PACKAGE DIMENSIONS



### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION F APPLIES BETWEEN F AND L.
  DIMENSION D AND J APPLY BETWEEN L AND K
  MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.022	0.41	0.55	
F	0.016	0.019	0.41	0.48	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
v	0.135		3 43		

STYLE 17:

PIN 1. COLLECTOR

2. BASE

3. EMITTER

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